

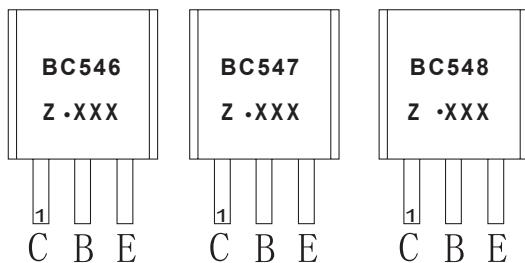
## TO-92 Plastic-Encapsulate Transistors

### **BC546 / BC547 / BC548 TRANSISTOR (NPN)**

#### **FEATURES**

- High Voltage
- Complement to BC556,BC557,BC558

#### **MARKING**



BC546,BC547,BC548=Device code

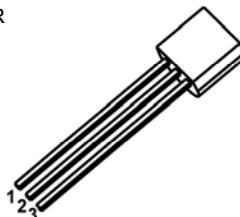
Solid dot=Green molding compound device,  
if none,the normal device

Z=Rank of  $h_{FE}$

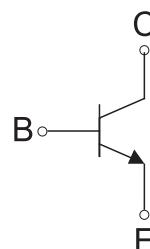
XXX=Code

#### **TO-92**

1. COLLECTOR
2. BASE
3. Emitter



#### **Equivalent Circuit**



#### **ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
BC546	TO-92	Bulk	1000pcs/Bag
BC546-TA	TO-92	Tape	2000pcs/Box
BC547	TO-92	Bulk	1000pcs/Bag
BC547-TA	TO-92	Tape	2000pcs/Box
BC548	TO-92	Bulk	1000pcs/Bag
BC548-TA	TO-92	Tape	2000pcs/Box

#### **MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{cbo}$	Collector-Base Voltage	BC546	80
		BC547	50
		BC548	30
$V_{ceo}$	Collector-Emitter Voltage	BC546	65
		BC547	45
		BC548	30
$V_{ebo}$	Emitter-Base Voltage	BC546	6
		BC547	6
		BC548	5
$I_c$	Collector Current-Continuous	0.1	A
$P_c$	Collector Power Dissipation	625	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	200	°C/W
$T_j$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-55~+150	°C

## ELECTRICAL CHARACTERISTICS

$T_a=25^\circ\text{C}$  unless otherwise specified

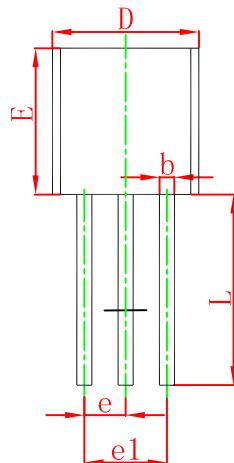
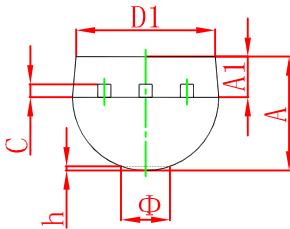
### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	BC546	$V_{(BR)CBO}$	$I_C = 0.1\text{mA}, I_E = 0$	80		
	BC547			50		
	BC548			30		
Collector-emitter breakdown voltage	BC546	$V_{(BR)CEO}$	$I_C = 1\text{mA}, I_B = 0$	65		
	BC547			45		
	BC548			30		
Emitter-base breakdown voltage	BC546	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}, I_C = 0$	6		
	BC547			6		
	BC548			5		
Collector cut-off current	BC546	$I_{CEO}$	$V_{CB} = 70\text{V}, I_E = 0$		0.1	$\mu\text{A}$
	BC547		$V_{CB} = 50\text{V}, I_E = 0$		0.1	$\mu\text{A}$
	BC548		$V_{CB} = 30\text{V}, I_E = 0$		0.1	$\mu\text{A}$
Collector cut-off current	BC546	$I_{CEO}$	$V_{CE} = 60\text{V}, I_B = 0$		0.1	$\mu\text{A}$
	BC547		$V_{CE} = 45\text{V}, I_B = 0$		0.1	$\mu\text{A}$
	BC548		$V_{CE} = 30\text{V}, I_B = 0$		0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$		$V_{EB} = 5\text{V}, I_C = 0$		0.1	$\mu\text{A}$
DC current gain	$h_{FE}^*$		$V_{CE} = 5\text{V}, I_C = 2\text{mA}$	110	800	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$		$I_C = 100\text{mA}, I_B = 5\text{mA}$		0.3	$\text{V}$
Base-emitter saturation voltage	$V_{BE(\text{sat})}$		$I_C = 100\text{mA}, I_B = 5\text{mA}$		1.1	$\text{V}$
Base-emitter voltage	$V_{BE}$	$V_{CE} = 5\text{V}, I_C = 2\text{mA}$		0.58	0.7	$\text{V}$
		$V_{CE} = 5\text{V}, I_C = 10\text{mA}$			0.75	$\text{V}$
Collector output capacitance	$C_{ob}$		$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$		4.5	$\text{pF}$
Transition frequency	$f_T$		$V_{CE} = 5\text{V}, I_C = 10\text{mA}, f = 100\text{MHz}$	150		$\text{MH}$

### CLASSIFICATION of $h_{FE}$

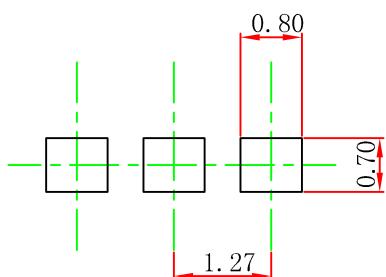
RANK	A	B	C
RANGE	110-220	200-450	420-800

## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

## TO-92 Suggested Pad Layout



### Note:

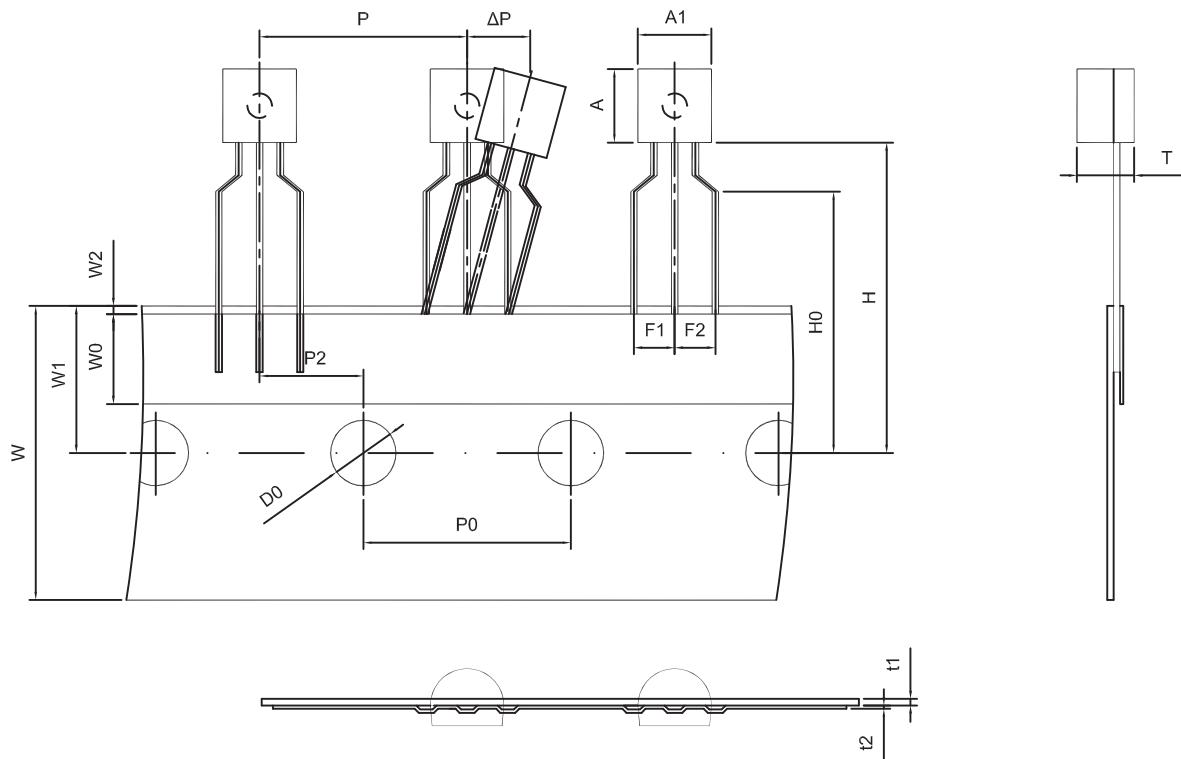
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$ mm.
3. The pad layout is for reference purposes only.

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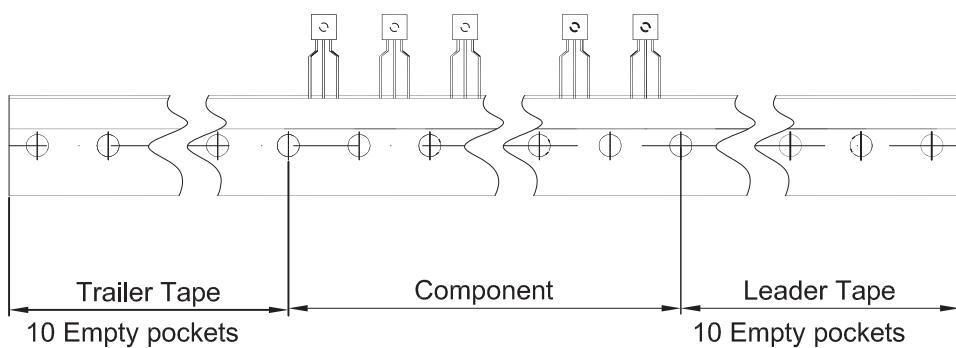
## TO-92 Tape and Reel

### TO-92 PACKAGE TAPEING DIMENSION



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250

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